



Product data sheet

1 Product profile

1.1 General description

Two planar PIN diodes in common anode configuration in a SOT323 small SMD plastic package.

1.2 Features and benefits

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- · Low series inductance
- For applications up to 3 GHz
- AEC-Q101 qualified

1.3 Applications

• RF attenuators and switches



2 Pinning information

Table 1. Discrete pinning							
Pin	Description	Simplified outline	Graphic symbol				
1	cathode 1						
2	cathode 2						
3	common connection	1 2 Top view	2 1 mgu320				

3 Ordering information

Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
BAP64-06W	-	plastic surface-mounted package; 3 leads	SOT323			

4 Marking

Table 3. Marking code						
Type number	Marking code					
BAP64-06W	V4%					

5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	continuous reverse voltage		-	100	V
l _F	continuous forward current		-	100	mA
P _{tot}	total power dissipation	T _{sp} ≤ 90 °C	-	240	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

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6 Thermal characteristics

Table 5. Thermal characteristics							
Symbol	Parameter	Conditions	Тур	Unit			
R _{th(j-sp)}	thermal resistance from junction to solder point		250	K/W			

7 Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
/ _F	forward voltage	I _F = 50 mA		-	0.95	1.1	V	
R	reverse current	V _R = 60 V		-	-	10	μA	
		V _R = 20 V		-	-	1	μA	
C _d	diode capacitance	f = 1 MHz (see Figure 1)		1				
		V _R = 0 V		-	0.52	-	pF	
		V _R = 1 V		-	0.37	-	pF	
		V _R = 20 V		-	0.23	0.35	pF	
r _D	diode forward resistance	f = 100 MHz (see <u>Figure 2</u>)			I			
		I _F = 0.5 mA	[1]	-	20	40	Ω	
		I _F = 1 mA	[1]	-	10	20	Ω	
		I _F = 10 mA	[1]	-	2	3.8	Ω	
		I _F = 100 mA	[1]	-	0.7	1.35	Ω	
ISL	isolation	V _R = 0 V (see <u>Figure 4</u>)						
		f = 900 MHz		-	18.5	-	dB	
		f = 1800 MHz		-	13.5	-	dB	
		f = 2450 MHz		-	10.9	-	dB	
L _{ins}	insertion loss	$I_F = 0.5 \text{ mA} \text{ (See Figure 3)}.$						
		f = 900 MHz		-	1.86	-	dB	
		f = 1800 MHz		-	2.06	-	dB	
		f = 2450 MHz		-	2.23	-	dB	
		I _F = 1 mA		1				
		f = 900 MHz		-	1.01	-	dB	
		f = 1800 MHz		-	1.06	-	dB	
		f = 2450 MHz		-	1.10	-	dB	
		I _F = 10 mA						
		f = 900 MHz		-	0.19	-	dB	
		f = 1800 MHz		-	0.21	-	dB	
		f = 2450 MHz		-	0.27	-	dB	
-ins	insertion loss	I _F = 100 mA						
		f = 900 MHz		-	0.08	-	dB	
		f = 1800 MHz		-	0.10	-	dB	
		f = 2450 MHz		-	0.16	-	dB	
				1				

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
τι	charge carrier life time	when switched from $I_F = 10 \text{ mA}$ to $I_R = 6 \text{ mA}$; $R_L = 100 \Omega$; measured at $I_R = 3 \text{ mA}$	-	1.55	-	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	-	1.6	-	nH

[1] Guaranteed on AQL basis; inspection level S4, AQL 1.0

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8 Graphical data





Diode inserted in series with a 50 Ω strip line circuit and biased via the analyzer T-network. T_{amb} = 25 °C.

(1) $I_F = 100 \text{ mA}$ (2) $I_F = 10 \text{ mA}$ (3) $I_F = 1 \text{ mA}$

Figure 3. Insertion loss of the diode as a function of frequency (typical values)



Diode zero-biased and inserted in series with a 50 Ω strip line circuit T_{amb} = 25 °C.

Figure 4. Isolation of the diode as a function of frequency (typical values)

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9 Package outline



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10 Revision history

Table 7. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
BAP64-06W v.3.2	20190212	Product data sheet	-	BAP64-06W v.3.1		
Modifications:	 aligned the last g 	raphic with the look and	feel of the other gra	phics		
BAP64-06W v.3.1	20190201	Product data sheet	-	BAP64-06W v.3		
Modifications:	 changed condition 	n for reverse current for	V _R from 100 V to 60	V		
BAP64-06W v.3	20181211	Product data sheet	-	BAP64-06W v.2		
Modifications: • Section 1.2 "Features and benefits" has been updated. • The "Legal information" pages have been updated.						
BAP64-06W v.2	20010417	Product data sheet	-	BAP64-06W v.1		

11 Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

[2] [3] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 12 February 2019 Document identifier: BAP64-06W